






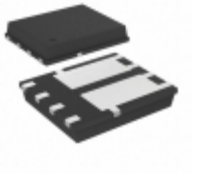

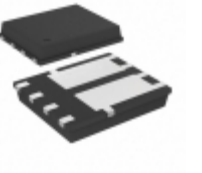
	<h2 style="color: red;">SI7872DP-T1-GE3</h2>
 <p>Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: SI7872DP-T1-GE3
	Hersteller / Marke: Electro-Films (EFI) / Vishay
	Teil der Beschreibung: MOSFET 2N-CH 30V 6.4A PPAK SO-8
	Datenblätter:  SI7872DP-T1-GE3.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 108567 pcs Stock Available.
Liefern von: Hong Kong	
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	SI7872DP-T1-GE3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET 2N-CH 30V 6.4A PPAK SO-8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	108567 pcs Stock
detaillierte Beschreibung	Mosfet Array 2 N-Channel (Half Bridge) 30V 6.4A 1.4W
Serie	LITTLE FOOT®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	1.4W
Verpackung / Gehäuse	PowerPAK® SO-8 Dual
Supplier Device-Gehäuse	PowerPAK® SO-8 Dual
Typ FET	2 N-Channel (Half Bridge)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	6.4A
Rds On (Max) @ Id, Vgs	22 mOhm @ 7.5A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	11nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)
Basisteilenummer	SI7872
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI7872DP-T1-GE3TR

SI7872DP-T1-GE3 ist neu im Original, Suche SI7872DP-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7872DP-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI7872DP-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI786LG-T1-E3 VISHAY SI786LG-T1-E3 VISHAY</p>	 <p>SI7880ADP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 40A PPAK SO-8</p>	 <p>SI7880ADP-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 40A PPAK SO-8</p>	 <p>SI7872DP SI SI7872DP SI</p>
 <p>SI7880ADP-T1-E3 Vishay / Siliconix MOSFET N-CH 30V 40A PPAK SO-8</p>	 <p>SI7872DP-T1-E3 Vishay / Siliconix MOSFET 2N-CH 30V 6.4A PPAK SO-8</p>	 <p>SI7880ADP-T1-GE3 Vishay / Siliconix MOSFET N-CH 30V 40A PPAK SO-8</p>	 <p>SI7872DP-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 30V 6.4A PPAK SO-8</p>

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|  SI7862DP-T1 |  SI7864ADP |  SI7864ADP-T1-GE3 |  SI7864DP-T1-GE3 |  SI7866ADP |
|  SI7866ADP-T1-E3 |  SI7866ADP-T1-E3 |  SI7866ADP-T1-GE3 |  SI7866ADP-T1-GE3 |  SI7866DP-T1 |
|  SI7866DP-T1-E3 |  SI7866DP-T1-GE3 |  SI7868ADP |  SI7868ADP-T1-E3 |  SI7868ADP-T1-E3 |
|  SI7868ADP-T1-GE3 |  SI7868ADP-T1-GE3 |  SI7868DP-T1 |  SI7868DP-T1-E3 |  SI7868DP-T1-GE3 |
|  SI786LG-T1 |  SI786LG-T1-E3 |  SI7872DP |  SI7872DP-T1-E3 |  SI7872DP-T1-E3 |
|  SI7872DP-T1-GE3 |  SI7880ADP-T1-E3 |  SI7880ADP-T1-E3 |  SI7880ADP-T1-GE3 |  SI7880ADP-T1-GE3 |
|  SI7880DP-T1-GE3 |  SI7882DP-T1-E3 |  SI7882DP-T1-E3 |  SI7882DP-T1-GE3 |  SI7882DP-T1-GE3 |
|  SI7884BDP |  SI7884BDP-T1-E3 |  SI7884BDP-T1-E3 |  SI7884BDP-T1-GE3 |  SI7884BDP-T1-GE3 |
|  SI7884DP-T1-E3 |  SI7884DP-T1-GE3 |  SI7886ADP-T1-E3 |  SI7886ADP-T1-E3 |  SI7886ADP-T1-GE3 |
|  SI7886ADP-T1-GE3 |  SI7886DP |  SI7886DP-T1 |  SI7886DP-T1-E3 |  SI7886DP-T1-GE3 |

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